## NSN 5961-01-177-4718

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-177-4718 **Inclosure Material:** Metal **Overall Length:** 1.218 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-111 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 breakdown voltage, collector-to-base, emitter open and 350.0 breakdown voltage, collector-to-emitter, base open and 15.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 47.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 30.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug and 1 wire hook Shelf Life: N/a

Demilitarization:

**Unit Of Measure:** 

Yes - demil/mli

## **NSN 5961-01-177-4718** Transistor - Page 2 of 2



Fiig:

A110a0